

HIGH VOLTAGE ULTRAFAST RECTIFIER

MAIN PRODUCT CHARACTERISTICS

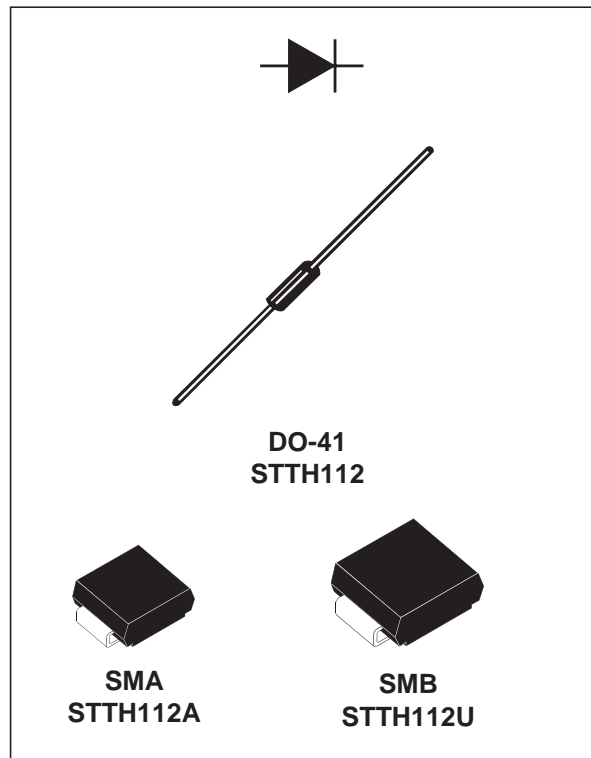
$I_{F(AV)}$	1 A
V_{RRM}	1200 V
$T_j(\text{max})$	175 °C
$V_F(\text{max})$	1.65 V

FEATURES AND BENEFITS

- Low forward voltage drop
- High reliability
- High surge current capability
- Soft switching for reduced EMI disturbances
- Planar technology

DESCRIPTION

The STTH112, which is using ST ultrafast high voltage planar technology, is specially suited for free-wheeling, clamping, snubbing, demagnetization in power supplies and other power switching applications.



ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		Value	Unit
V_{RRM}	Repetitive peak reverse voltage		1200	V
$V_{(RMS)}$	RMS voltage		850	V
$I_{F(AV)}$	Average forward current	$T_I = 85^\circ\text{C} \quad \delta = 0.5$	1	A
		$T_I = 115^\circ\text{C} \quad \delta = 0.5$		
		$T_I = 125^\circ\text{C} \quad \delta = 0.5$		
I_{FSM}	Forward surge current $t = 8.3 \text{ ms}$	DO-41	20	A
		SMA		
		SMB		
T_{stg}	Storage temperature range		- 50 + 175	°C
T_j	Maximum operating junction temperature		+ 175	°C

THERMAL PARAMETERS

Symbol	Parameter			Value	Unit
R _{th(j-l)}	Junction to lead	L = 10 mm	DO-41	45	°C/W
			SMA	30	
			SMB	25	
R _{th(j-a)}	Junction to ambient	L = 10 mm	DO-41	110	

STATIC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Tests conditions		Min.	Typ.	Max.	Unit
I _R	Reverse leakage current	V _R = 1200V	T _j = 25°C			5	µA
			T _j = 125°C			50	
V _F	Forward voltage drop	I _F = 1 A	T _j = 25°C			1.9	V
			T _j = 125°C		1.17	1.65	

To evaluate the maximum conduction losses use the following equation :
 $P = 1.35 \times I_{F(AV)} + 0.3 \times I_{F(RMS)}^2$

DYNAMIC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Tests conditions		Min.	Typ.	Max.	Unit
t _{rr}	Reverse recovery time	I _F = 0.5 A I _{rr} = 0.25 A I _R = 1A	T _j = 25°C			75	ns
t _{fr}	Forward recovery time	I _F = 1 A dI _F /dt = 50 A/µs V _{FR} = 1.1 x V _{Fmax}	T _j = 25°C			500	ns
V _{FP}	Forward recovery voltage					30	V

Fig. 1: Conduction losses versus average current.

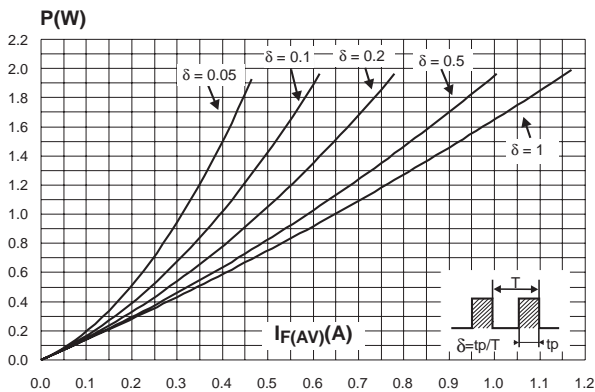


Fig. 2: Forward voltage drop versus forward current.

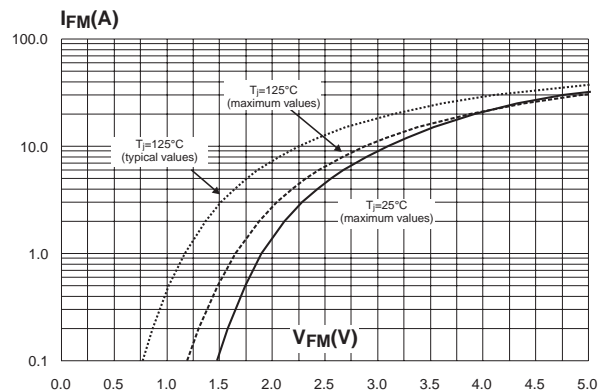


Fig. 3-1: Relative variation of thermal impedance junction ambient versus pulse duration (epoxy FR4, $L_{leads} = 10\text{mm}$) (DO-41).

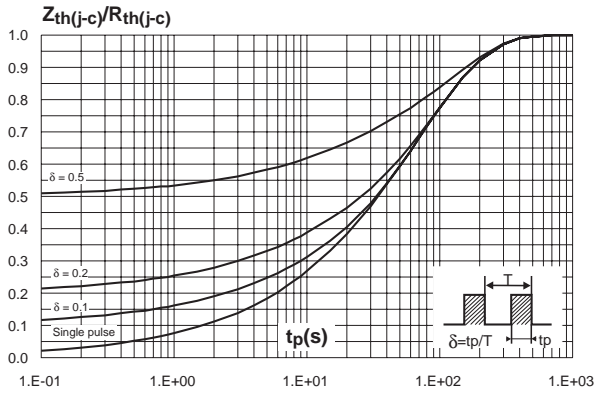


Fig. 3-2: Relative variation of thermal impedance junction ambient versus pulse duration (epoxy FR4) (SMA).

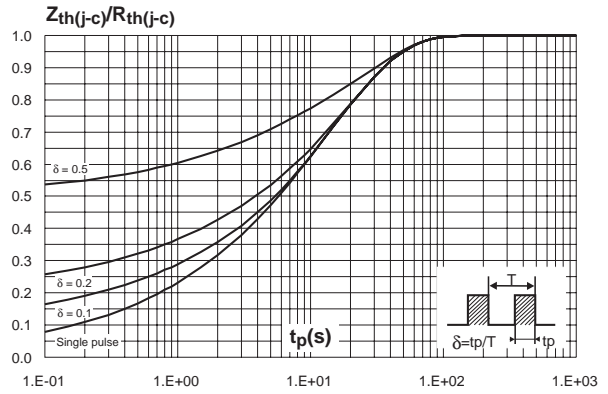


Fig. 3-3: Relative variation of thermal impedance junction ambient versus pulse duration (epoxy FR4)(SMB).

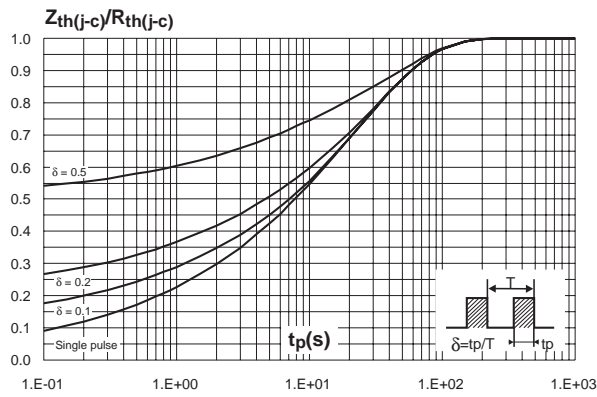


Fig. 4-1: Thermal resistance junction to ambient versus copper surface under each lead (epoxy printed circuit board FR4, copper thickness: $35\mu\text{m}$) (DO-41, SMB).

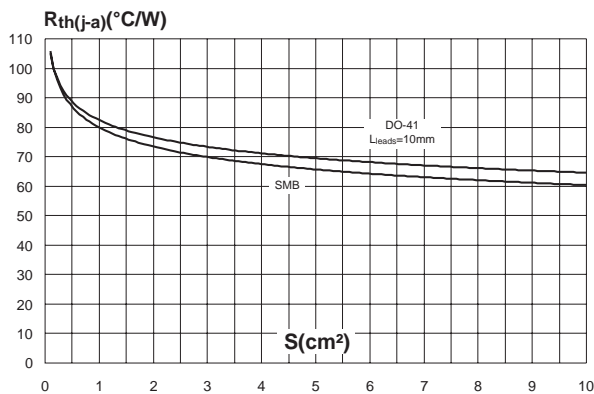
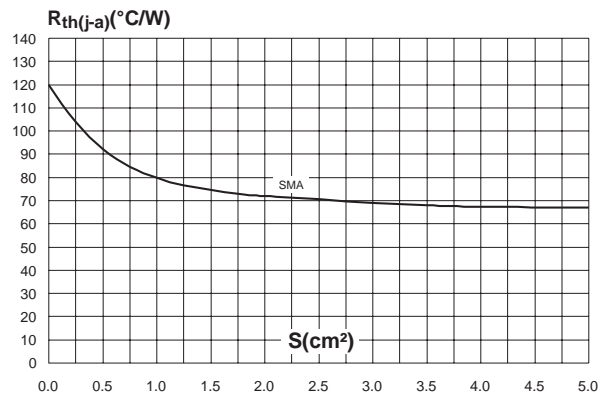
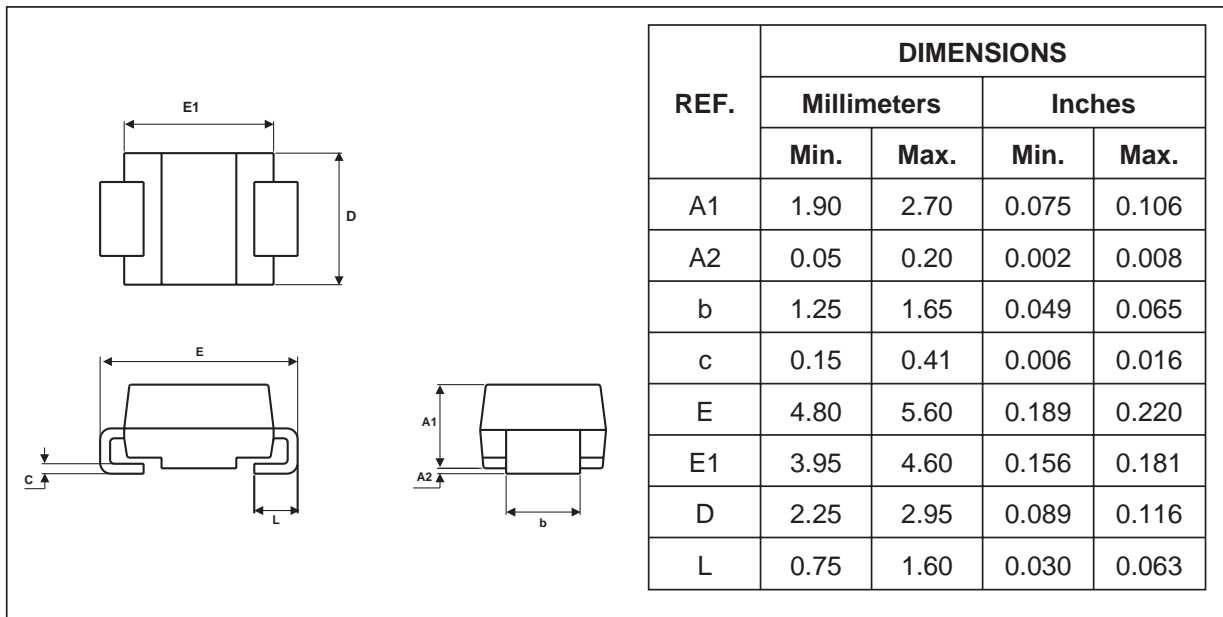


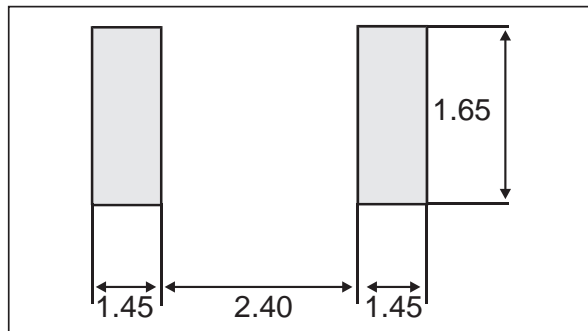
Fig. 4-2: Thermal resistance junction to ambient versus copper surface under each lead (epoxy printed circuit board FR4, copper thickness: $35\mu\text{m}$) (SMA).



PACKAGE MECHANICAL DATA
SMA



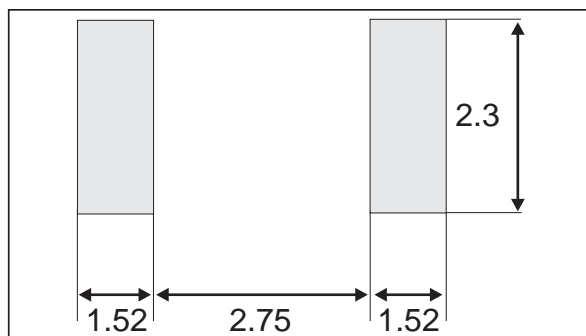
FOOTPRINT (in millimeters)



PACKAGE MECHANICAL DATA
SMB

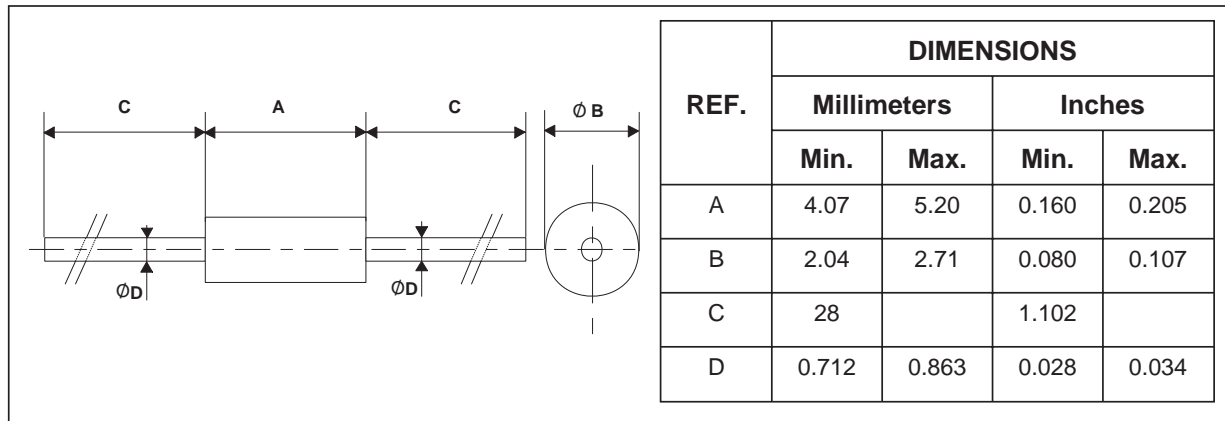
REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A1	1.90	2.45	0.075	0.096
A2	0.05	0.20	0.002	0.008
b	1.95	2.20	0.077	0.087
c	0.15	0.41	0.006	0.016
E	5.10	5.60	0.201	0.220
E1	4.05	4.60	0.159	0.181
D	3.30	3.95	0.130	0.156
L	0.75	1.60	0.030	0.063

FOOTPRINT (in millimeters)



STTH112/A/U

PACKAGE MECHANICAL DATA DO-41



Ordering code	Marking	Package	Weight	Base qty	Delivery mode
STTH112	STTH112	DO-41	0.34 g	2000	Ammopack
STTH112A	H12	SMA	0.068 g	5000	Tape & reel
STTH112U	U12	SMB	0.11 g	2500	Tape & reel
STTH112RL	STTH112	DO-41	0.34 g	5000	Tape & reel

- Epoxy meets UL 94,V0

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